



TV22..F

Fast Recovery Diode

Replaces March 1998 version, DS4210-2.2

DS4210-3.0 January 2000

APPLICATIONS

- Induction Heating
- A.C. Motor Drives
- Snubber Diode
- Welding
- High Frequency Rectification
- UPS

FEATURES

- Thermal Fatigue Free Pressure Contact
- High Surge Capability
- Low Recovery Charge

VOLTAGE RATINGS

Type Number	Repetitive Peak Reverse Voltage V_{RRM} V	Conditions
TV22 16F M or K	1600	$V_{RSM} = V_{RRM} + 100V$
TV22 14F M or K	1400	
TV22 12F M or K	1200	
TV22 10F M or K	1000	
TV22 08F M or K	800	
TV22 06F M or K	600	

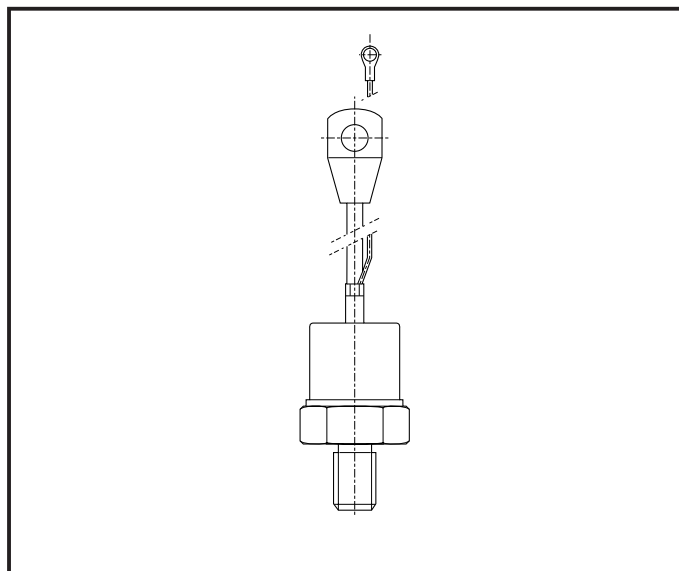
For 3/4" 16 UNF thread, add suffix K, e.g. TV22 16FK.

For M16 thread, add suffix M, e.g. TV22 16FM.

For stud anode add 'R' to type number, e.g. TV22 16FMR.

KEY PARAMETERS

V_{RRM}	1600V
$I_{F(AV)}$	305A
I_{FSM}	5000A
Q_r	70 μ C
t_{rr}	3.2 μ s



Outline type codes: DO9.

See Package Details for further information.

CURRENT RATINGS

Symbol	Parameter	Conditions	Max.	Units
$I_{F(AV)}$	Mean forward current	Half wave resistive load, $T_{case} = 65^{\circ}C$	305	A
$I_{F(RMS)}$	RMS value	$T_{case} = 65^{\circ}C$	346	A

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SURGE RATINGS

Symbol	Parameter	Conditions	Max.	Units
I_{FSM}	Surge (non-repetitive) forward current	10ms half sine; with 0% V_{RRM} , $T_j = 150^\circ\text{C}$	5.0	kA
I^2t	I^2t for fusing		125×10^3	A^2s
I_{FSM}	Surge (non-repetitive) forward current	10ms half sine; with 50% V_{RRM} , $T_j = 150^\circ\text{C}$	-	kA
I^2t	I^2t for fusing		-	A^2s

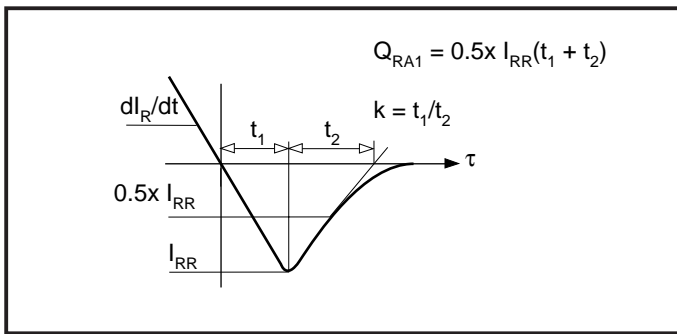
THERMAL AND MECHANICAL DATA

Symbol	Parameter	Conditions	Min.	Max.	Units
$R_{th(j-c)}$	Thermal resistance - junction to case	dc	-	0.16	$^\circ\text{C}/\text{W}$
$R_{th(c-h)}$	Thermal resistance - case to heatsink	Mounting torque 35.0Nm with mounting compound	-	0.06	$^\circ\text{C}/\text{W}$
T_{vj}	Virtual junction temperature	On-state (conducting)	-	150	$^\circ\text{C}$
T_{stg}	Storage temperature range		-55	175	$^\circ\text{C}$
-	Mounting torque		30.0	35.0	Nm

CHARACTERISTICS

Symbol	Parameter	Conditions	Typ.	Max.	Units
V_{FM}	Forward voltage	At 750A peak, $T_{case} = 25^\circ\text{C}$	-	1.6	V
I_{RRM}	Peak reverse current	At V_{RRM} , $T_{case} = 150^\circ\text{C}$	-	40	mA
t_{rr}	Reverse recovery time	$I_F = 750\text{A}$, $di_{RR}/dt = 100\text{A}/\mu\text{s}$ $T_{case} = 125^\circ\text{C}$, $V_R = 100\text{V}$	-	3.2	μs
Q_{RA1}	Recovered charge (50% chord)		-	70	μC
I_{RM}	Reverse recovery current		-	43	A
K	Soft factor		1.8	-	-
V_{TO}	Threshold voltage	At $T_{vj} = 150^\circ\text{C}$	-	1.0	V
r_T	Slope resistance	At $T_{vj} = 150^\circ\text{C}$	-	0.8	$\text{m}\Omega$
V_{FRM}	Forward recovery voltage	$di/dt = 1000\text{A}/\mu\text{s}$, $T_j = 125^\circ\text{C}$	-	-	V

DEFINITION OF K FACTOR AND Q_{RA1}



CURVES

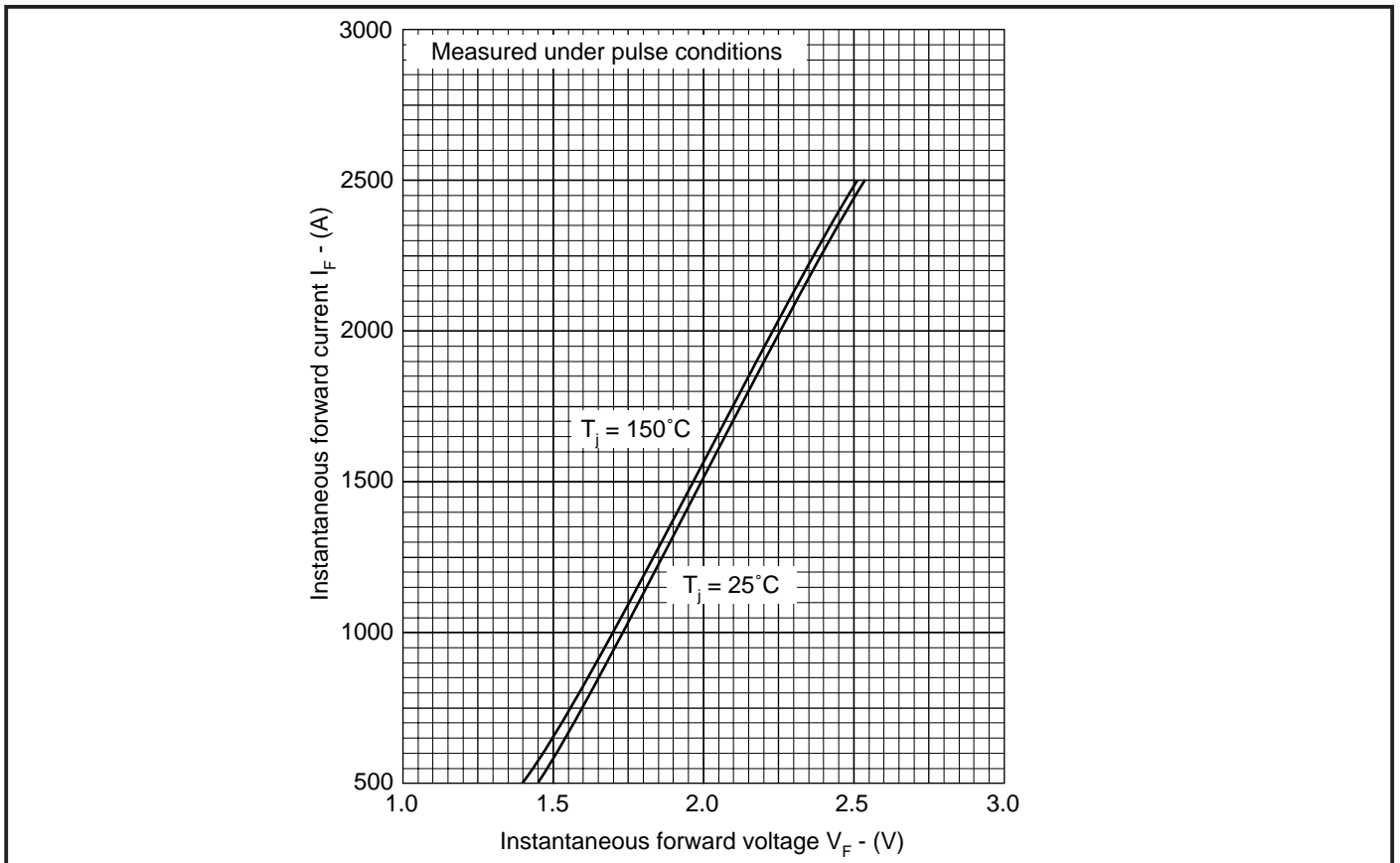


Fig.1 Maximum (limit) forward characteristics

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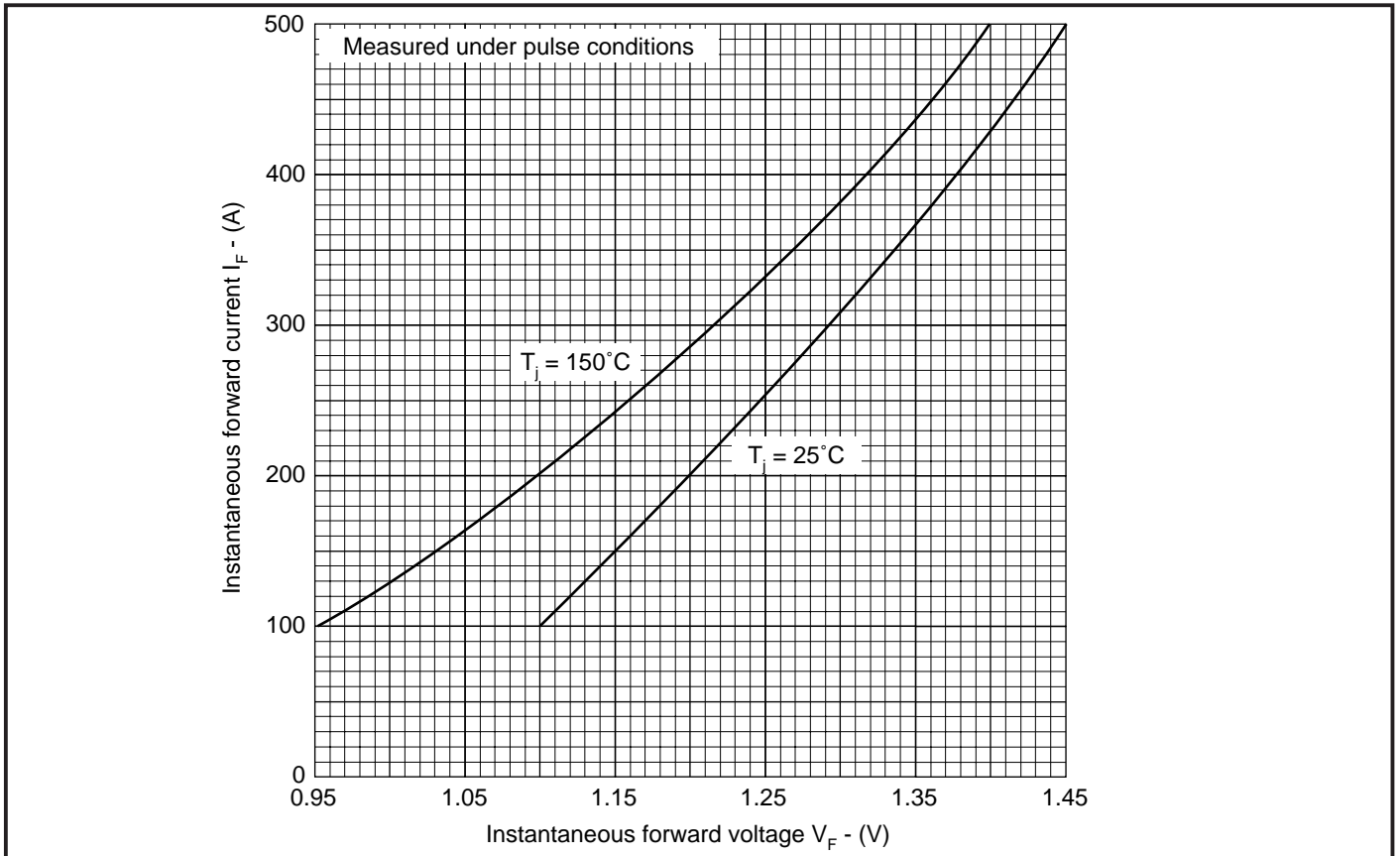


Fig.2 Maximum (limit) forward characteristics

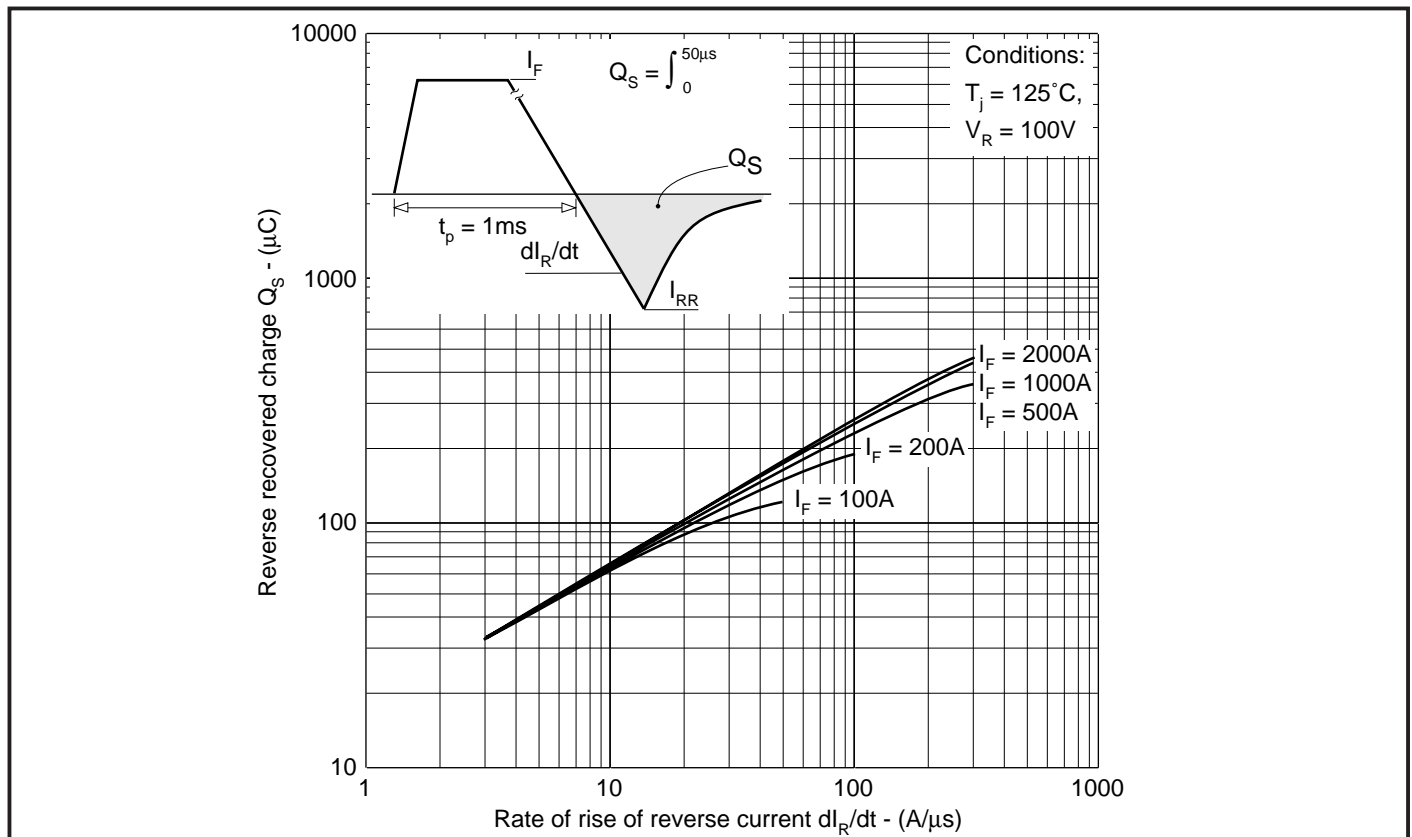


Fig.3 Recovered charge

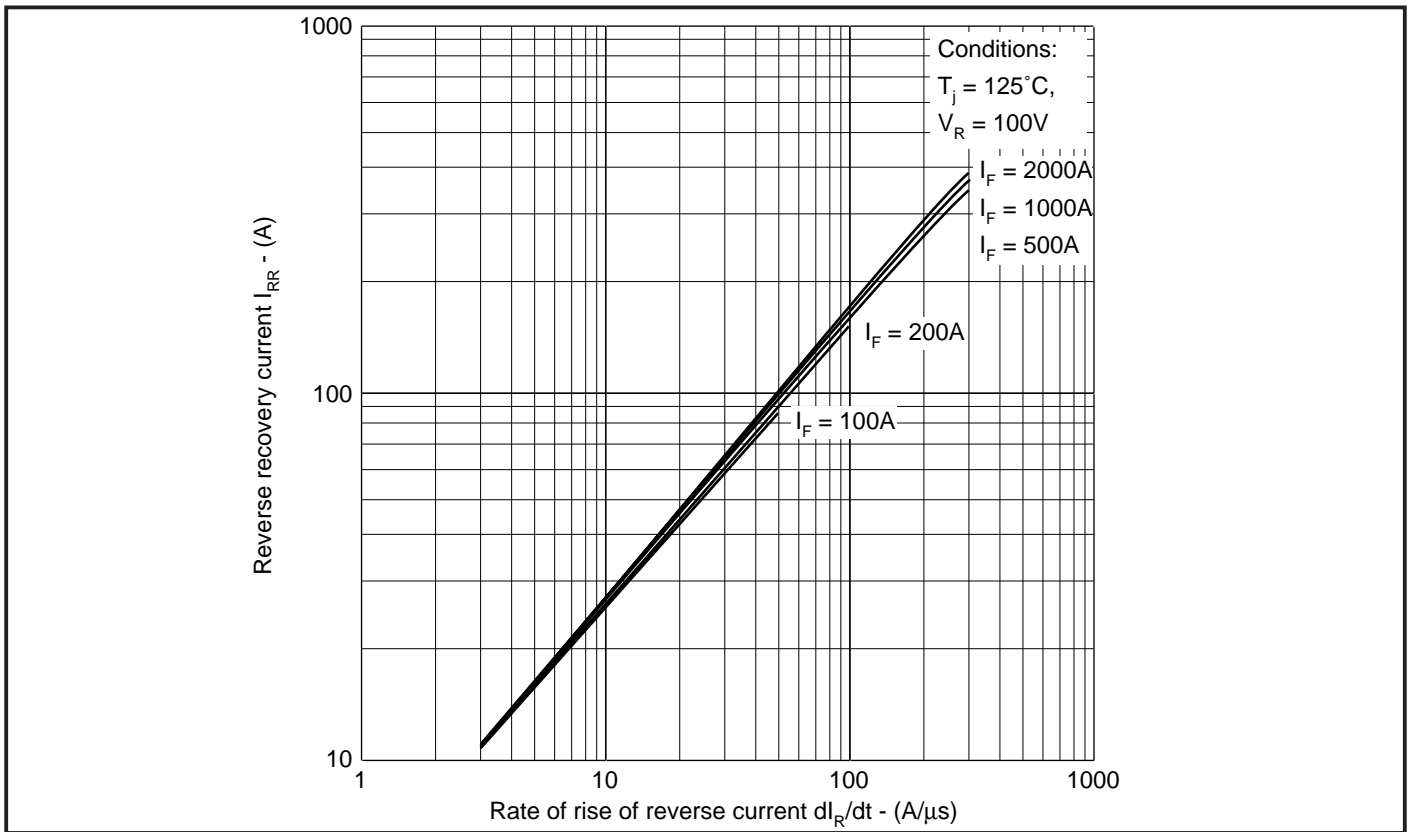


Fig.4 Typical reverse recovery current vs rate of rise of reverse current

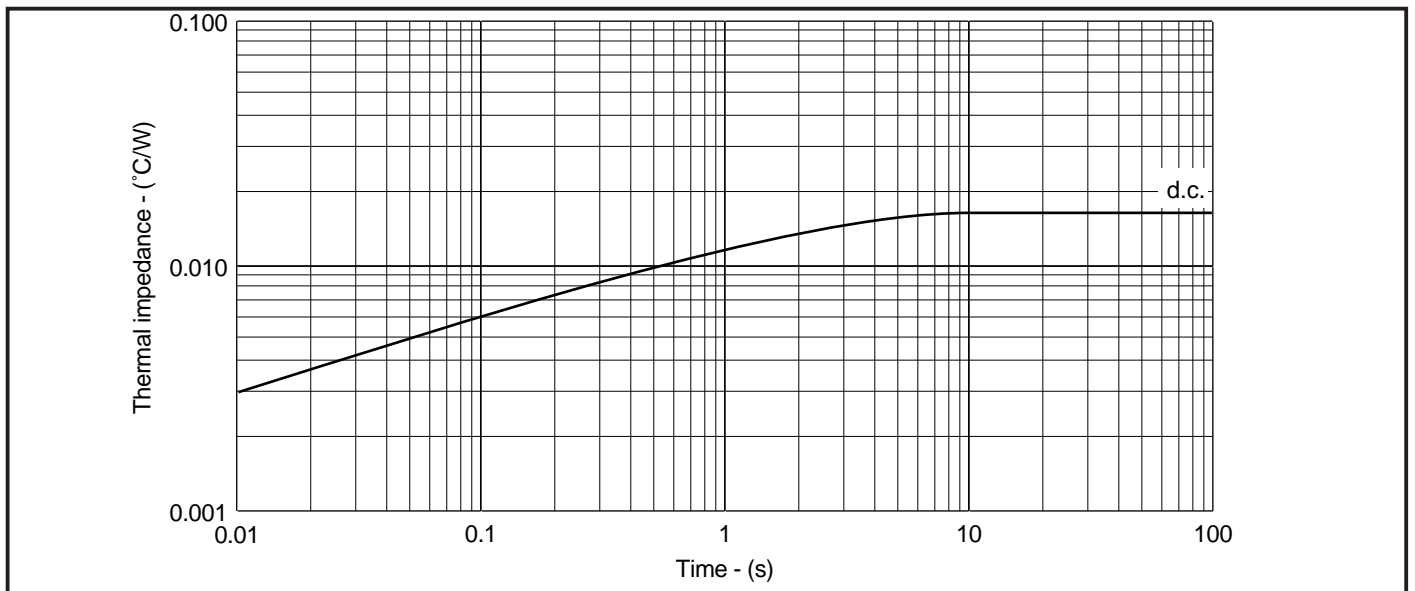
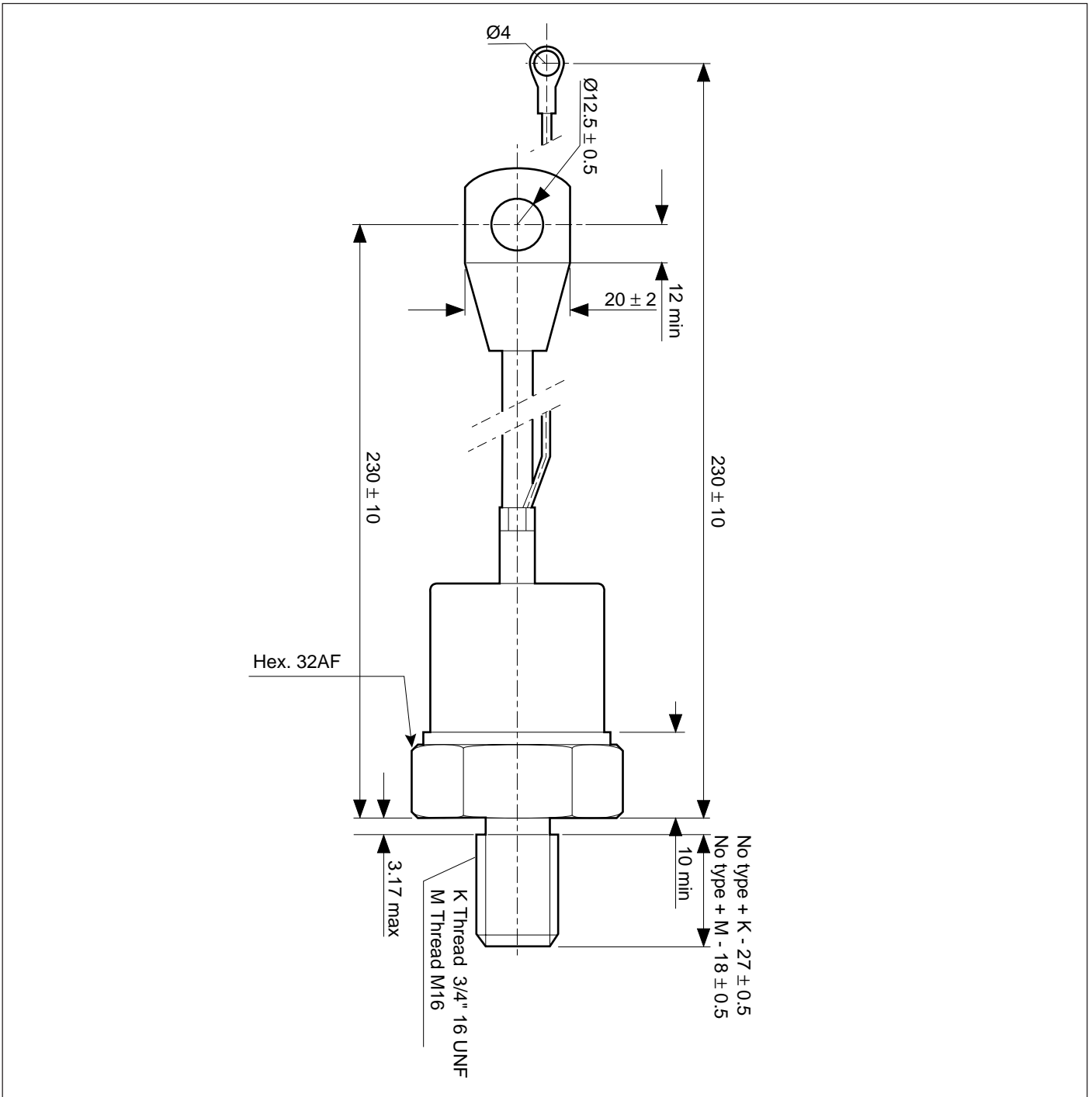


Fig.5 Maximum (limit) transient thermal impedance - junction to case - ($^\circ\text{C/W}$)

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PACKAGE DETAILS

For further package information, please contact your local Customer Service Centre. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



ASSOCIATED PUBLICATIONS

Title	Application Note Number
Calculating the junction temperature or power semiconductors	AN4506
Thyristor and diode measurement with a multi-meter	AN4853
Use of V_{TO} , r_T on-state characteristic	AN5001

POWER ASSEMBLY CAPABILITY

The Power Assembly group was set up to provide a support service for those customers requiring more than the basic semiconductor, and has developed a flexible range of heatsink / clamping systems in line with advances in device types and the voltage and current capability of our semiconductors.

We offer an extensive range of air and liquid cooled assemblies covering the full range of circuit designs in general use today. The Assembly group continues to offer high quality engineering support dedicated to designing new units to satisfy the growing needs of our customers.

Using the up to date CAD methods our team of design and applications engineers aim to provide the Power Assembly Complete solution (PACs).

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Preliminary Information: The product is in design and development. The datasheet represents the product as it is understood but details may change.

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No Annotation: The product parameters are fixed and the product is available to datasheet specification.

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